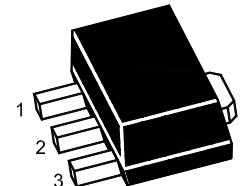


## Features

- 150 Volt  $V_{CEO}$
- 1 Amp continuous current



1.Base 2.Collector 3.Emitter  
SOT-89 Plastic Package

## Absolute maximum ratings

Parameter	Symbol	Value	Unit
Collector-base voltage	$V_{CBO}$	170	V
Collector-emitter voltage	$V_{CEO}$	150	V
Emitter-base voltage	$V_{EBO}$	5	V
Continuous collector current	$I_C$	1	A
Peak pulse current	$I_{CM}$	2	A
Base current	$I_B$	200	mA
Power dissipation at $T_{amb} = 25^\circ C$	$P_{tot}$	1	W
Operating and storage temperature range	$T_j:T_{stg}$	-65 to +150	°C

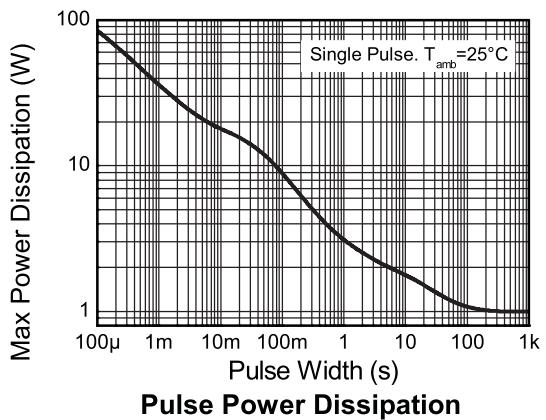
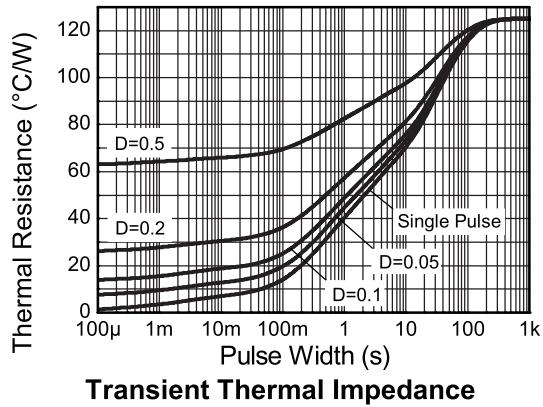
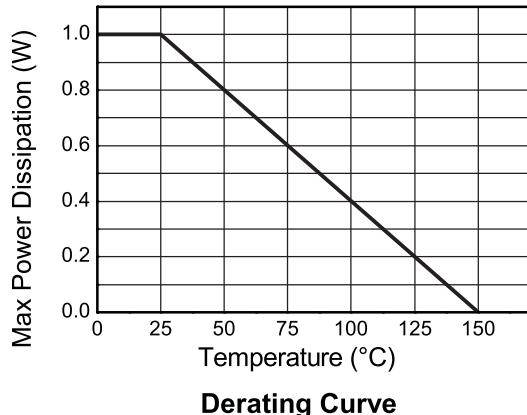
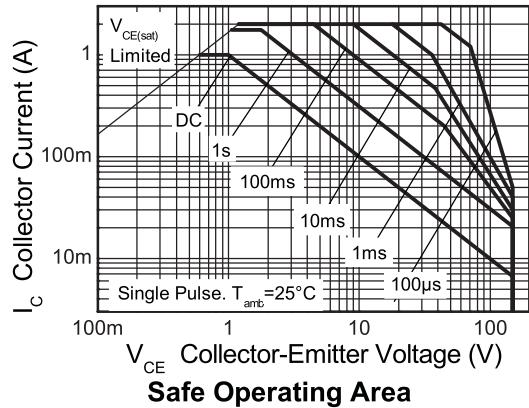
## Electrical characteristics (at $T_{amb} = 25^\circ C$ )

Parameter	Symbol	Min.	Max.	Unit	Conditions
Breakdown voltages	$V_{(BR)CBO}$	170		V	$I_C=100\mu A$
	$V_{CEO(sus)}$	150		V	$I_C=10mA^{(*)}$
	$V_{(BR)EBO}$	5		V	$I_E=100\mu A$
Collector cut-off currents	$I_{CBO}, I_{CES}$		100	nA	$V_{CB}=150V, V_{CE}=150V$
Emitter cut-off current	$I_{EBO}$		100	nA	$V_{EB}=4V$
Emitter saturation voltages	$V_{CE(sat)}$		0.2	V	$I_C=250mA, I_B=25mA^{(*)}$
			0.3	V	$I_C=500mA, I_B=50mA^{(*)}$
	$V_{BE(sat)}$		1.0	V	$I_C=500mA, I_B=50mA^{(*)}$
Base-emitter turn on voltage	$V_{BE(on)}$		1.0	V	$I_C=500mA, V_{CE}=10V^{(*)}$
Static forward current transfer ratio	$h_{FE}$	100	300		$I_C=1mA, V_{CE}=10V$
		100			$I_C=250mA, V_{CE}=10V^{(*)}$
		50			$I_C=500mA, V_{CE}=10V^{(*)}$
		10			$I_C=1A, V_{CE}=10V^{(*)}$
Transition frequency	$f_T$	100		MHz	$I_C=50mA, V_{CE}=10V$ $f=100MHz$
Collector-base breakdown voltage	$C_{obo}$		10	pF	$V_{CB}=10V, f=1MHz$

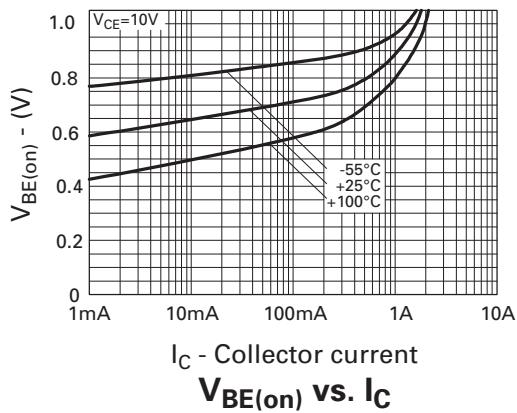
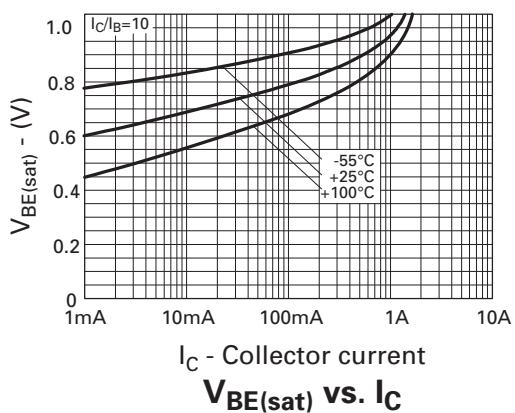
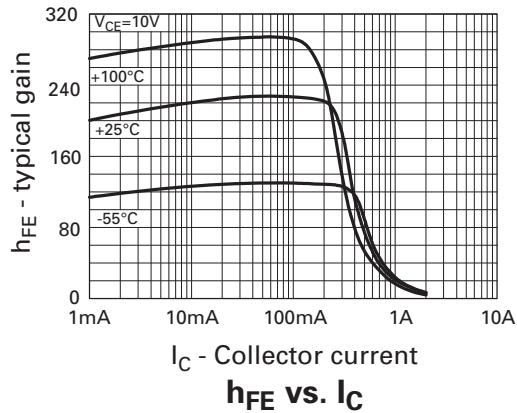
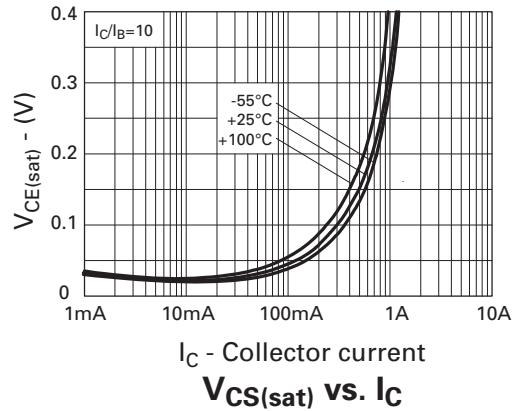
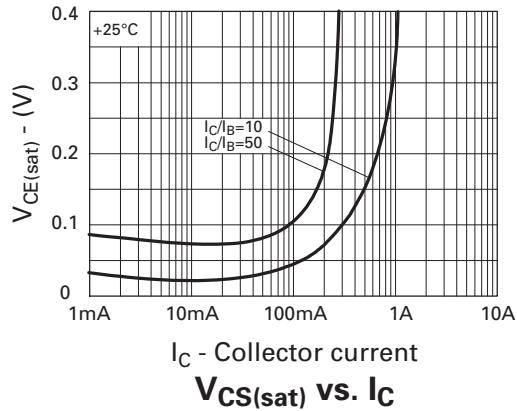
### NOTES:

(\*) Measured under pulsed conditions. Pulse width = 300μs. Duty cycle ≤2%

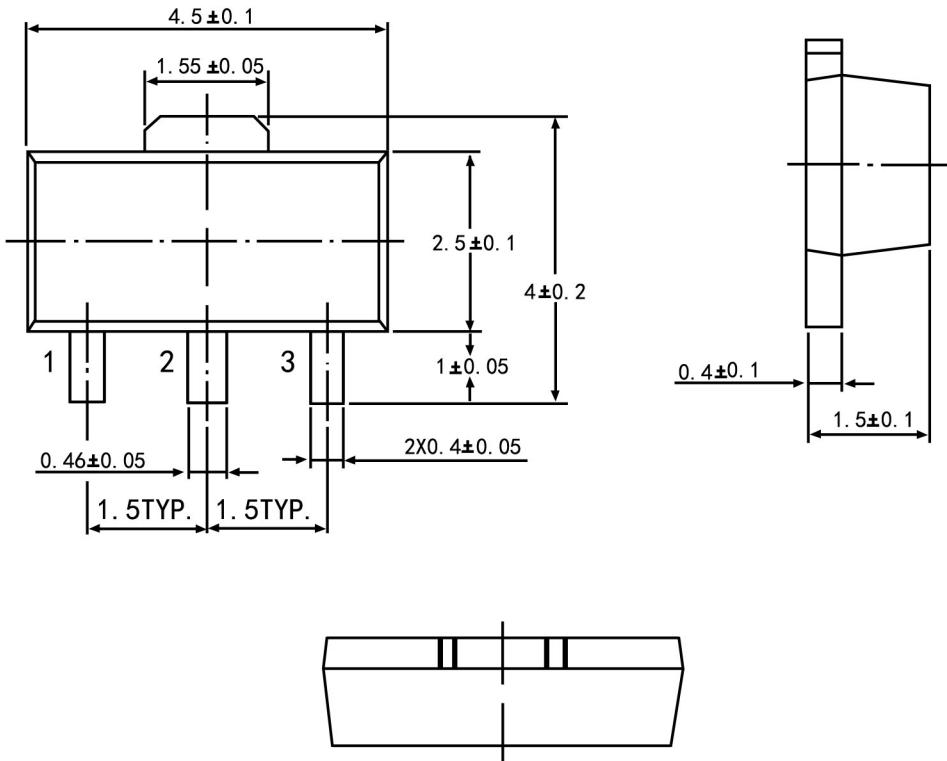
## Typical characteristics



### Typical characteristics



## SOT-89 PACKAGE OUTLINE



Symbol	Dimension in Millimeters	
	Min	Max
A	1.40	1.60
B	0.44	0.62
B1	0.35	0.54
C	0.35	0.44
D	4.40	4.60
D1	1.62	1.83
E	2.29	2.60
e	1.50 Typ	
H	3.94	4.25
H1	2.63	2.93
L	0.89	1.20
All Dimensions In mm		

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